Silicon-based integrated optics: waveguide technology to microphotonics p. 3
Light emission in aperiodic thue-morse dielectrics p. 15
Photoluminescent coupled multiple microcavity structures made of porous silicon p. 21
Raman gain in silicon using highly confined waveguide structure p. 27
Computer simulation of charging and erasing transients of a Ge/Si hetero-nanocrystal-based flash memory p. 33
Threshold voltage shift in hetero-nanocrystal floating gate flash memory p. 39
Structural characterization and coulomb blockade of a-SiN[subscript x]/Nanocrystalline Si/a-SiN[subscript x] asymmetric double-barrier structures p. 45
Evolution of the luminescence spectrum during the dry and steam oxidation of SiGe films p. 51
Towards a Si/SiGe quantum cascade laser for terahertz applications p. 59
Recent results on the road to a SiGe quantum cascade laser p. 69
The emission of terahertz radiation from doped silicon devices p. 81
Progress in the growth and characterization of Ge quantum dots and islands p. 93
Growth and overgrowth of Ge/Si quantum dots: an observation by atomic resolution HAADF-STEM imaging p. 105
Si[subscript 1-x]Ge[subscript x] nanocrystals observed by EFTEM: influence of the dry and wet oxidation process p. 111
Uniform dome-shaped self-assembled Ge islands by UHV/CVD after boron pre-deposition p. 117
Classical versus Ab initio structural relaxation: electronic excitations and optical properties of Ge nanocrystals embedded in a SiC matrix p. 121
Origin of the multi-exponential decay dynamics in light-emitting silicon nanocrystals p. 129
Improved optoelectronic characteristics of nanocrystalline porous silicon by high-pressure water vapor annealing p. 141
Theory of large-scale electronic structure calculation and nanostructures formed in silicon cleavage simulation: surface reconstruction, step and bending p. 147
Precipitation of highly luminescent phases from PECVD Si suboxides p. 153
Pump-probe experiments on low loss silica waveguides containing Si nanocrystals p. 159
Multi-color luminescence from nanocrystalline silicon p. 165
Improvement of operating voltage and luminescent properties in nanocrystalline silicon electroluminescent device p. 171
Electric force microscopy of individually charged silicon nanoparticles p. 179
Quasiballistic electron emission from planarized nanocrystalline-Si cold cathode p. 189
Enhancing the sound pressure of thermally induced ultrasonic emitter based on nanocrystalline porous silicon p. 195
Charge transport in silicon nanocrystal arrays p. 201
Possible operation of periodically layered nanocrystalline porous silicon as an acoustic band crystal device p. 207
Thermal conductivity of porous silicon evaluated from phase characteristics of photoacoustic spectroscopy p. 213
Structural modifications of nc-Si/SiO[subscript 2] superlattices by localized photo-induced heating p. 219
Anisotropically nanostructured silicon: a first-principle approach p. 225
Preparation of the atomically straight step-edge Si (111) substrates as templates for nanostructure formation

Surface cusp formation in Si homoepitaxy

Synthesis of microcrystalline silicon films by low energy electron-beam-induced deposition at cryogenic temperature

Self-limited photo-assisted synthesis of silicon nanocrystals

Nucleation and growth processes of silicon nanowires

Size control and phonon confinement of silicon nanowires synthesized by laser ablation

Complex diameter modulations in silicon carbide nanowire growth

Silicon nanowires : doping dependent n- and p-channel FET behavior

Fabrication and electrical characterization of silicon nanowire arrays

Metal-free growth of Si/SiO[subscript 2] nanowires by annealing SiO[subscript x] (x<2) films deposited by PECVD

Nanorings, nanopillars and nanospikes on Si(111) by modified nanosphere lithography : fabrication and application

Fabrication of a regular array of atomic silicon wires on silicon

Characterization of SiC nanowires grown by APCVD using single precursors

Growth and characterization of SiOx nanowires by VLS and SLS growth mechanism

Optical properties of Ge nanowires grown on silicon (100) and (111) substrates

Carrier transport in one-dimensional Ge nanowires/Si substrate heterojunctions

Formation of hydrogen-passivated silicon nanochains by pulsed laser ablation without thermal annealing

Analysis of growth rate of silicon nanowires

Pump-probe experiments on Er coupled Si-nanocrystals rib-loaded waveguides

Location of Er atoms with respect to Si nanoclusters in luminescent Er and Si co-implanted silicates

CMOS compatible erbium coupled Si nanocrystal thin films for micro photonics

Hydrogen passivation of Er and Si nanocrystallites in Er-doped SiO[subscript 2] - increase in photoluminescence

Optical properties of silicates co-doped with Si and Er[superscript 3+] ions

Luminescence of rare earth doped Si/Al/SiO[subscript 2] co-sputtered films

Optical activation of Si nanowires using Er-doped sol-gel derived silica

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